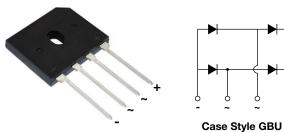
GBU25H08



Vishay General Semiconductor

Single In-Line Bridge Rectifier



Case Style GBU

LINKS TO ADDITIONAL RESOURCES



PRIMARY CHARACTERISTICS				
I _{F(AV)}	25 A			
V _{RRM}	800 V			
I _{FSM}	350 A			
V _F at I _F = 12.5 A (125 °C)	0.86 V			
T _J max.	175 °C			
Package	GBU			
Circuit configuration	In-line			

FEATURES

- UL recognition file number E312394
- Glass passivated pellet chip junction
- Solder dip 275 °C max. 10 s, per JESD 22-B106
- Ideal for printed circuit boards
- High surge current capability
- High case dielectric strength of 2000 $V_{\text{RMS}},\,1$ minute
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

TYPICAL APPLICATIONS

General purpose use in AC/DC bridge full wave rectification for switching power supply, home applications, and white-goods applications specially or telecom power supply, game PC

MECHANICAL DATA

Case: GBU

Molding compound meets UL 94 V-0 flammability rating Base P/N-M3 - halogen-free, RoHS-compliant, and industrial grade

Terminals: matte tin plated leads, solderable per J-STD-002 and JESD22-B102

M3 suffix meet JESD 201 class 1A whisker test

Polarity: as marked on body

Mounting Torque: 10 cm-kg (8.8 inches-lbs) max.

Recommended Torque: 5.7 cm-kg (5 inches-lbs)

MAXIMUM RATINGS ($T_A = 25 \text{ °C}$ unless otherwise noted)					
PARAMETER		SYMBOL	GBU25H08	UNIT	
Device marking code		GBU25H08			
Maximum repetitive peak reverse voltage	V _{RRM}	800	V		
Maximum RMS voltage	V _{RMS}	560	V		
Maximum DC blocking voltage		V _{DC}	800	V	
Maximum average forward rectified output current at	$T_C = 50 \ ^\circ C$	I _O ⁽¹⁾	25	Α	
	T _A = 25 °C	I _O ⁽²⁾	4.5		
Non-repetitive peak forward surge current 8.3 ms single sine-wave, $T_J = 25 \ ^\circ C$		I _{FSM}	350	А	
Non-repetitive peak forward surge current 1.0 ms single sine-wave, $T_J = 25 ^\circ\text{C}$		I _{FSM}	700	A	
Rating for fusing (t < 8.3 ms)		l ² t	508	A ² s	
Operating junction and storage temperature range		T _J , T _{STG}	-55 to +175	°C	

Notes

⁽¹⁾ Unit case mounted on aluminum plate heatsink

⁽²⁾ Units mounted on PCB without heatsink

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GBU25H08



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ELECTRICAL CHARACTERISTICS ($T_J = 25 \text{ °C}$ unless otherwise noted)						
PARAMETER	TEST CONDITIONS		SYMBOL	TYP.	MAX.	UNIT
Maximum instantaneous forward voltage drop	I _F = 12.5 A	T _J = 25 °C	V _F ⁽¹⁾	0.97	1.05	V
per diode	$I_{\rm F} = 12.5 {\rm A}$	T _J = 125 °C	VF ()	0.86	-	v
Maximum DC reverse current at rated DC	V _B = 800 V	T _J = 25 °C	I _B ⁽²⁾	-	10	
blocking voltage per diode	$v_{\rm R} = 000 v$	T _J = 125 °C	'R \-/	45	-	μA
Typical reverse recovery time	$I_F = 0.5 \text{ A}, I_R = 1.0 \text{ A}, I_{rr} = 0.25 \text{ A}$		t _{rr}	3500	-	ns
Typical junction capacitance per diode	4.0 V, 1 MHz		CJ	100	-	pF

Notes

 $^{(1)}\,$ Pulse test: 300 μs pulse width, 1 % duty cycle

⁽²⁾ Pulse test: pulse width \leq 40 ms

THERMAL CHARACTERISTICS ($T_A = 25$ °C unless otherwise noted)					
PARAMETER	SYMBOL	GBU25H08	UNIT		
Typical thermal resistance	R _{0JA} ⁽¹⁾	24	°C/W		
Typical thermal resistance	R _{0JC} ⁽²⁾	4			

Notes

⁽¹⁾ Without heatsink, free air

(2) With heatsink

ORDERING INFORMATION						
PREFERRED P/N	UNIT WEIGHT (g)	PREFERRED PACKAGE CODE	BASE QUANTITY	DELIVERY MODE		
GBU25H08-M3/P	3.87	Р	20	Tube		

RATINGS AND CHARACTERISTICS CURVES (T_A = 25 °C unless otherwise noted)

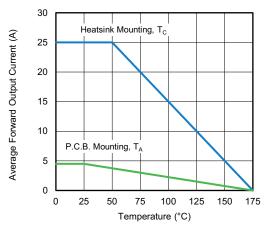


Fig. 1 - Derating Curve Output Rectified Current

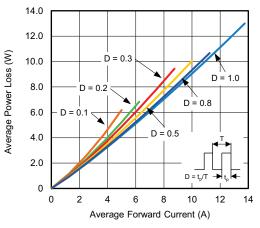
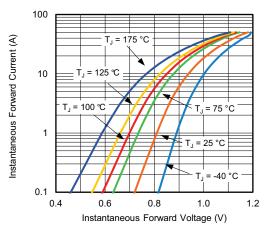


Fig. 2 - Maximum Non-Repetitive Peak Forward Surge Current Per Diode

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Fig. 3 - Typical Forward Characteristics Per Diode

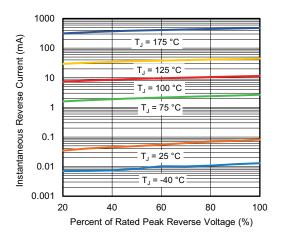


Fig. 4 - Typical Reverse Leakage Characteristics Per Diode

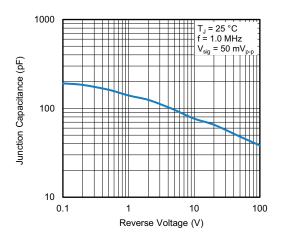


Fig. 5 - Typical Junction Capacitance Per Diode

Junction to Ambient Transient Thermal Impedance (°C/W) 1 10 1 0.1 0.01 0.1 10 100 1000 1 t - Pulse Duration (s)

100

Fig. 6 - Typical Transient Thermal Impedance Per Diode

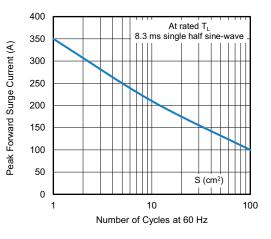


Fig. 7 - Peak Forward Surge Current

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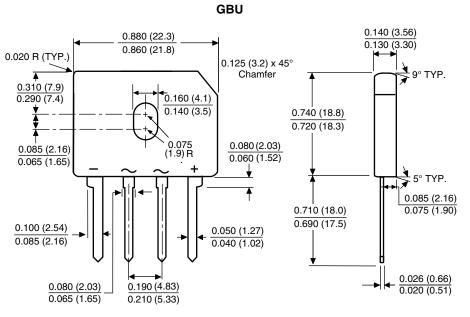
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PACKAGE OUTLINE DIMENSIONS in inches (millimeters)



Polarity shown on front side of case, positive lead by beveled corner



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